



# AiP74LVC1G17

## Single Buffer Schmitt Trigger

### Product Specification

**Specification Revision History:**

Version	Date	Description
2017-07-A1	2017-07	New
2021-05-A2	2021-05	Modify Transfer Characteristics Parameter
2021-09-A3	2021-09	Modify ambient temperature to $-40^{\circ}\text{C}\sim+105^{\circ}\text{C}$ and add electrical characteristics of $-40^{\circ}\text{C}\sim+105^{\circ}\text{C}$ ; Modify ordering information
2021-12-A4	2021-12	Modify ordering information
2022-03-A5	2022-03	Modify ordering information note 1



## 1、 General Description

The AiP74LVC1G17 provides a buffer function with Schmitt trigger input. It is capable of transforming slowly changing input signals into sharply defined outputs.

The input can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### Features:

- Wide supply voltage range from 1.65V to 5.5V
- $\pm 24\text{mA}$  output drive ( $V_{CC}=3.0\text{V}$ )
- CMOS low power consumption
- Latch-up performance exceeds 250mA
- Direct interface with TTL levels
- Unlimited rise and fall times
- Input accepts voltages up to 5V
- Specified from  $-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$
- Packaging information: SOT-23-5/SOT-353

### Ordering Information:

#### Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
AiP74LVC1G17GB235.TR	SOT-23-5	AFXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.9mm×1.6mm Pin spacing: 0.95mm
AiP74LVC1G17GC353.TR	SOT-353	AFXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.1mm×1.3mm Pin spacing: 0.65mm

Note 1: "XX" refers to variable content, meaning year and package batch serial number.

Note 2: If the physical information is inconsistent with the ordering information, please refer to the actual product.



## 2、Block Diagram And Pin Description

### 2.1、Block Diagram

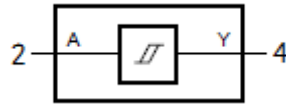


Figure 1. Logic symbol



Figure 2. IEC logic symbol

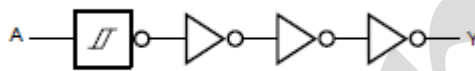
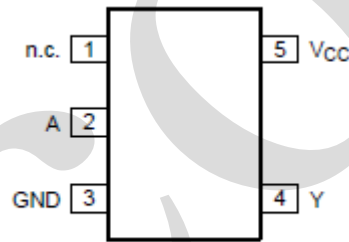


Figure 3. Logic diagram

### 2.2、Pin Configurations



### 2.3、Pin Description

Pin No.	Pin Name	Description
1	n.c.	not connected
2	A	data input
3	GND	ground (0V)
4	Y	data output
5	V <sub>CC</sub>	supply voltage

### 2.4、Function Table

Input	Output
A	Y
L	L
H	H

Note: H=HIGH voltage level; L=LOW voltage level.



## 3、Electrical Parameter

### 3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	$V_{CC}$	-	-0.5	+6.5	V
input voltage	$V_I$	-	-0.5	+6.5	V
output voltage	$V_O$	Active mode	-0.5	$V_{CC}+0.5$	V
		Power-down mode; $V_{CC}=0V$	-0.5	+6.5	V
input clamping current	$I_{IK}$	$V_I < 0V$	-50	-	mA
output clamping current	$I_{OK}$	$V_O > V_{CC}$ or $V_O < 0V$	-	$\pm 50$	mA
output current	$I_O$	$V_O=0V$ to $V_{CC}$	-	$\pm 50$	mA
supply current	$I_{CC}$	-	-	+100	mA
ground current	$I_{GND}$	-	-100	-	mA
storage temperature	$T_{stg}$	-	-65	+150	$^{\circ}C$
total power dissipation	$P_{tot}$	-	-	250	mW
Soldering temperature	$T_L$	10s	250		$^{\circ}C$

### 3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	$V_{CC}$	-	1.65	-	5.5	V
input voltage	$V_I$	-	0	-	5.5	V
output voltage	$V_O$	Active mode	0	-	$V_{CC}$	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	$T_{amb}$	-	-40	-	+105	$^{\circ}C$



### 3.3、Electrical Characteristics

#### 3.3.1、DC Characteristics 1

( $T_{amb} = -40^{\circ}C$  to  $+85^{\circ}C$ , voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
HIGH-level output voltage	$V_{OH}$	$V_I = V_{T+}$ or $V_{T-}$	$I_O = -100\mu A$ ; $V_{CC} = 1.65V$ to $5.5V$	$V_{CC} - 0.1$	-	-	V
			$I_O = -4mA$ ; $V_{CC} = 1.65V$	1.2	-	-	V
			$I_O = -8mA$ ; $V_{CC} = 2.3V$	1.9	-	-	V
			$I_O = -12mA$ ; $V_{CC} = 2.7V$	2.2	-	-	V
			$I_O = -24mA$ ; $V_{CC} = 3.0V$	2.3	-	-	V
			$I_O = -32mA$ ; $V_{CC} = 4.5V$	3.8	-	-	V
LOW-level output voltage	$V_{OL}$	$V_I = V_{T+}$ or $V_{T-}$	$I_O = 100\mu A$ ; $V_{CC} = 1.65V$ to $5.5V$	-	-	0.10	V
			$I_O = 4mA$ ; $V_{CC} = 1.65V$	-	-	0.45	V
			$I_O = 8mA$ ; $V_{CC} = 2.3V$	-	-	0.30	V
			$I_O = 12mA$ ; $V_{CC} = 2.7V$	-	-	0.40	V
			$I_O = 24mA$ ; $V_{CC} = 3.0V$	-	-	0.55	V
			$I_O = 32mA$ ; $V_{CC} = 4.5V$	-	-	0.55	V
input leakage current	$I_I$	$V_I = 5.5V$ or GND; $V_{CC} = 0V$ to $5.5V$	-	$\pm 0.1$	$\pm 1$	$\mu A$	
power-off leakage current	$I_{OFF}$	$V_I$ or $V_O = 5.5V$ ; $V_{CC} = 0V$	-	$\pm 0.1$	$\pm 2$	$\mu A$	
supply current	$I_{CC}$	$V_I = 5.5V$ or GND; $I_O = 0A$ ; $V_{CC} = 1.65V$ to $5.5V$	-	0.1	4	$\mu A$	
additional supply current	$\Delta I_{CC}$	per pin; $V_I = V_{CC} - 0.6V$ ; $I_O = 0A$ ; $V_{CC} = 2.3V$ to $5.5V$	-	5	500	$\mu A$	
input capacitance	$C_I$	-	-	5.0	-	pF	

Note: All typical values are measured at maximum  $V_{CC}$  and  $T_{amb} = 25^{\circ}C$ .

#### 3.3.2、DC Characteristics 2

( $T_{amb} = -40^{\circ}C$  to  $+105^{\circ}C$ , voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
HIGH-level output voltage	$V_{OH}$	$V_I = V_{T+}$ or $V_{T-}$	$I_O = -100\mu A$ ; $V_{CC} = 1.65V$ to $5.5V$	$V_{CC} - 0.1$	-	-	V
			$I_O = -4mA$ ; $V_{CC} = 1.65V$	0.95	-	-	V
			$I_O = -8mA$ ; $V_{CC} = 2.3V$	1.7	-	-	V
			$I_O = -12mA$ ; $V_{CC} = 2.7V$	1.9	-	-	V
			$I_O = -24mA$ ; $V_{CC} = 3.0V$	2.0	-	-	V
			$I_O = -32mA$ ; $V_{CC} = 4.5V$	3.4	-	-	V
LOW-level output voltage	$V_{OL}$	$V_I = V_{T+}$ or $V_{T-}$	$I_O = 100\mu A$ ; $V_{CC} = 1.65V$ to $5.5V$	-	-	0.10	V
			$I_O = 4mA$ ; $V_{CC} = 1.65V$	-	-	0.70	V
			$I_O = 8mA$ ; $V_{CC} = 2.3V$	-	-	0.45	V
			$I_O = 12mA$ ; $V_{CC} = 2.7V$	-	-	0.60	V
			$I_O = 24mA$ ; $V_{CC} = 3.0V$	-	-	0.80	V
			$I_O = 32mA$ ; $V_{CC} = 4.5V$	-	-	0.80	V



input leakage current	$I_I$	$V_I=5.5V$ or GND; $V_{CC}=0V$ to 5.5V	-	-	$\pm 1$	$\mu A$
power-off leakage current	$I_{OFF}$	$V_I$ or $V_O=5.5V$ ; $V_{CC}=0V$	-	-	$\pm 2$	$\mu A$
supply current	$I_{CC}$	$V_I=5.5V$ or GND; $I_O=0A$ ; $V_{CC}=1.65V$ to 5.5V	-	-	4	$\mu A$
additional supply current	$\Delta I_{CC}$	per pin; $V_I=V_{CC}-0.6V$ ; $I_O=0A$ ; $V_{CC}=2.3V$ to 5.5V	-	-	500	$\mu A$

Note: All typical values are measured at maximum  $V_{CC}$  and  $T_{amb}=25^\circ C$ .

### 3.3.3、AC Characteristics 1

( $T_{amb}=-40^\circ C$  to  $+85^\circ C$ , voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
A to Y propagation delay	$t_{pd}$	see Figure 5	$V_{CC}=1.65V$ to 1.95V	1.0	4.1	11.0	ns
			$V_{CC}=2.3V$ to 2.7V	0.7	2.8	6.5	ns
			$V_{CC}=2.7V$	0.7	3.2	6.5	ns
			$V_{CC}=3.0V$ to 3.6V	0.7	3.0	5.5	ns
			$V_{CC}=4.5V$ to 5.5V	0.7	2.2	5.0	ns
Power dissipation capacitance	$C_{PD}$	$V_{CC}=3.3V$ ; $V_I=GND$ to $V_{CC}$	-	16.6	-	pF	

Note:

[1] Typical values are measured at  $T_{amb}=25^\circ C$  and  $V_{CC}=1.8V$ , 2.5V, 2.7V, 3.3V and 5.0V respectively.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in uW).

$$P_D=C_{PD}\times V_{CC}^2\times f_i\times N+\sum(C_L\times V_{CC}^2\times f_o)$$
 where:

$f_i$ =input frequency in MHz;

$f_o$ =output frequency in MHz;

$C_L$ =output load capacitance in pF;

$V_{CC}$ =supply voltage in V;

$N$ =number of inputs switching;

$\sum(C_L\times V_{CC}^2\times f_o)$ =sum of outputs.

### 3.3.4、AC Characteristics 2

( $T_{amb}=-40^\circ C$  to  $+105^\circ C$ , voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
A to Y propagation delay	$t_{pd}$	see Figure 5	$V_{CC}=1.65V$ to 1.95V	1.0	-	14.0	ns
			$V_{CC}=2.3V$ to 2.7V	0.7	-	8.5	ns
			$V_{CC}=2.7V$	0.7	-	8.5	ns
			$V_{CC}=3.0V$ to 3.6V	0.7	-	7.0	ns
			$V_{CC}=4.5V$ to 5.5V	0.7	-	6.5	ns

Note:

[1] Typical values are measured at  $T_{amb}=25^\circ C$  and  $V_{CC}=1.8V$ , 2.5V, 2.7V, 3.3V and 5.0V respectively.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .



### 3.3.5、 Transfer Characteristics 1

( $T_{amb}=-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ , voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
positive-going threshold voltage	$V_{T+}$	see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	0.82	1.02	1.2	V
			$V_{CC}=2.3\text{V}$	1.03	1.25	1.45	V
			$V_{CC}=3.0\text{V}$	1.29	1.5	1.71	V
			$V_{CC}=4.5\text{V}$	1.84	2.15	2.41	V
			$V_{CC}=5.5\text{V}$	2.19	2.6	2.91	V
negative-going threshold voltage	$V_{T-}$	see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	0.45	0.6	0.75	V
			$V_{CC}=2.3\text{V}$	0.64	0.8	0.96	V
			$V_{CC}=3.0\text{V}$	0.86	1.1	1.34	V
			$V_{CC}=4.5\text{V}$	1.35	1.75	2.09	V
			$V_{CC}=5.5\text{V}$	1.61	2.15	2.59	V
hysteresis voltage	$V_H$	see Figure 6, Figure 7 and Figure 8	$V_{CC}=1.8\text{V}$	0.24	0.4	0.54	V
			$V_{CC}=2.3\text{V}$	0.26	0.4	0.57	V
			$V_{CC}=3.0\text{V}$	0.27	0.42	0.64	V
			$V_{CC}=4.5\text{V}$	0.28	0.45	0.65	V
			$V_{CC}=5.5\text{V}$	0.29	0.47	0.75	V

### 3.3.6、 Transfer Characteristics 2

( $T_{amb}=-40^{\circ}\text{C}$  to  $+105^{\circ}\text{C}$ , voltages are referenced to GND (ground = 0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
positive-going threshold voltage	$V_{T+}$	see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	0.79	-	1.2	V
			$V_{CC}=2.3\text{V}$	1.00	-	1.45	V
			$V_{CC}=3.0\text{V}$	1.26	-	1.71	V
			$V_{CC}=4.5\text{V}$	1.81	-	2.41	V
			$V_{CC}=5.5\text{V}$	2.16	-	2.91	V
negative-going threshold voltage	$V_{T-}$	see Figure 6 and Figure 7	$V_{CC}=1.8\text{V}$	0.45	-	0.78	V
			$V_{CC}=2.3\text{V}$	0.64	-	0.99	V
			$V_{CC}=3.0\text{V}$	0.86	-	1.37	V
			$V_{CC}=4.5\text{V}$	1.35	-	2.12	V
			$V_{CC}=5.5\text{V}$	1.61	-	2.62	V
hysteresis voltage	$V_H$	see Figure 6, Figure 7 and Figure 8	$V_{CC}=1.8\text{V}$	0.17	-	0.54	V
			$V_{CC}=2.3\text{V}$	0.20	-	0.57	V
			$V_{CC}=3.0\text{V}$	0.21	-	0.64	V
			$V_{CC}=4.5\text{V}$	0.22	-	0.65	V
			$V_{CC}=5.5\text{V}$	0.23	-	0.75	V



### 4、 Testing Circuit

#### 4.1、 AC Testing Circuit

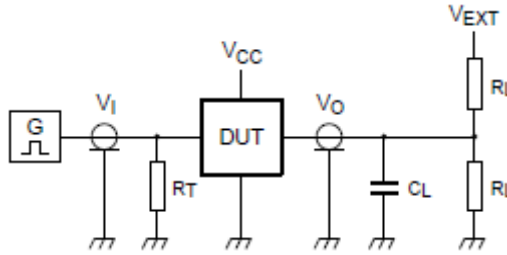


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

$R_L$ =Load resistance.

$C_L$ =Load capacitance including jig and probe capacitance.

$R_T$ =Termination resistance; should be equal to the output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$ =External voltage for measuring switching times.

#### 4.2、 AC Testing Waveforms

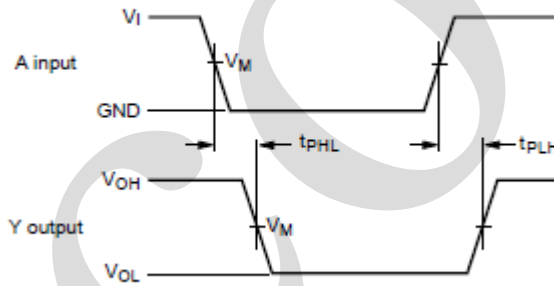


Figure 5. The data input (A) to output (Y) propagation delays

#### 4.3、 Transfer Characteristics Waveforms

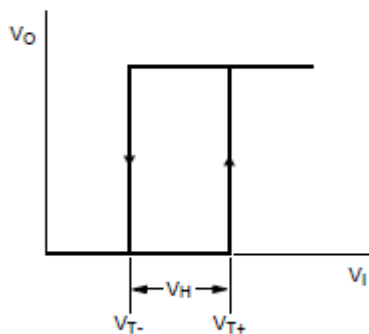


Figure 6. Transfer characteristic



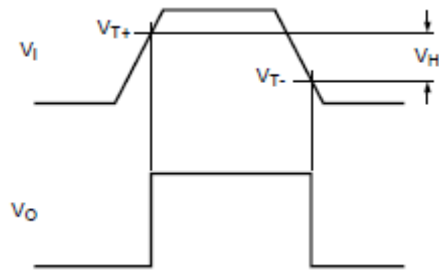
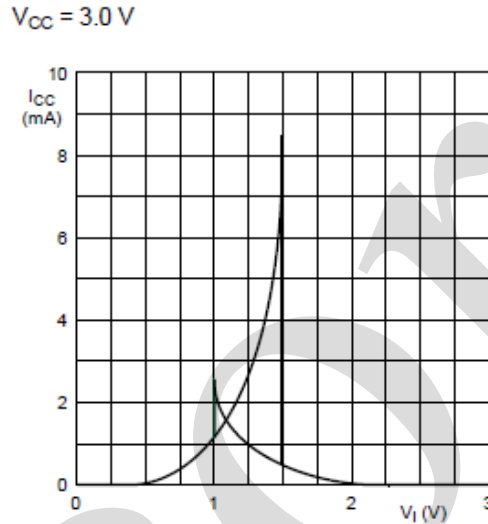
Figure 7. Definition of  $V_{T+}$ ,  $V_{T-}$  and  $V_H$ 

Figure 8. Typical transfer characteristics

#### 4.4. Measurement Points

Supply voltage	Input	Output
$V_{CC}$	$V_M$	$V_M$
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

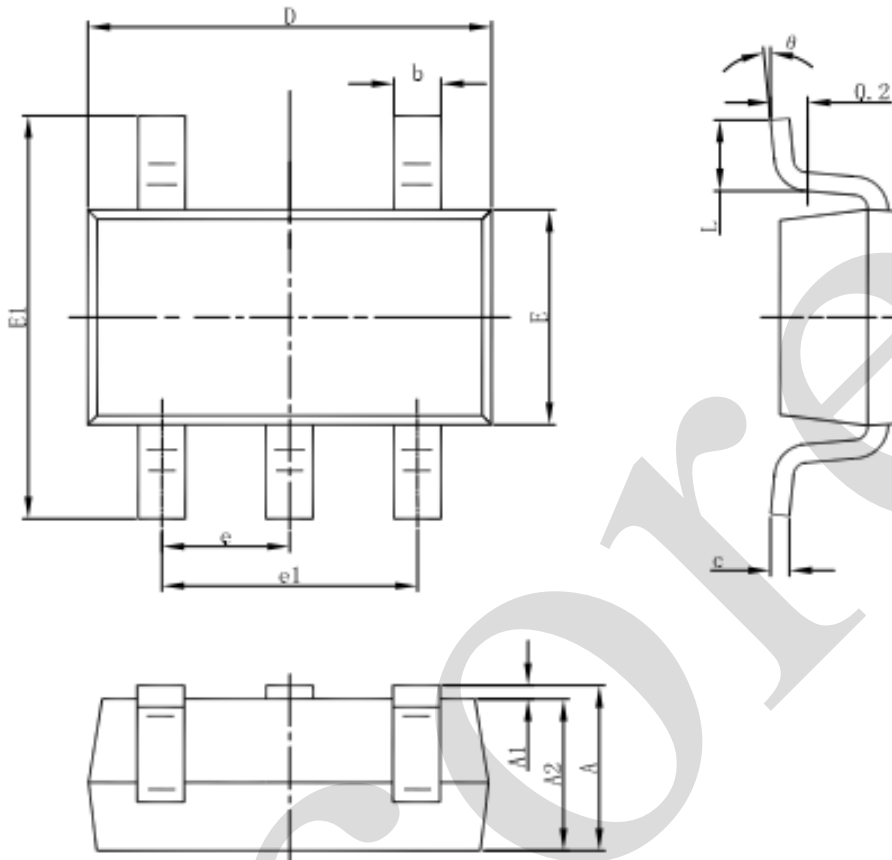
#### 4.5. Test Data

Supply voltage	Input		Load		$V_{EXT}$
$V_{CC}$	$V_I$	$t_r = t_f$	$C_L$	$R_L$	$t_{PLH}, t_{PHL}$
1.65V to 1.95V	$V_{CC}$	$\leq 2.0ns$	30pF	1k $\Omega$	open
2.3V to 2.7V	$V_{CC}$	$\leq 2.0ns$	30pF	500 $\Omega$	open
2.7V	2.7V	$\leq 2.5ns$	50pF	500 $\Omega$	open
3.0V to 3.6V	2.7V	$\leq 2.5ns$	50pF	500 $\Omega$	open
4.5V to 5.5V	$V_{CC}$	$\leq 2.5ns$	50pF	500 $\Omega$	open



## 5、Package Information

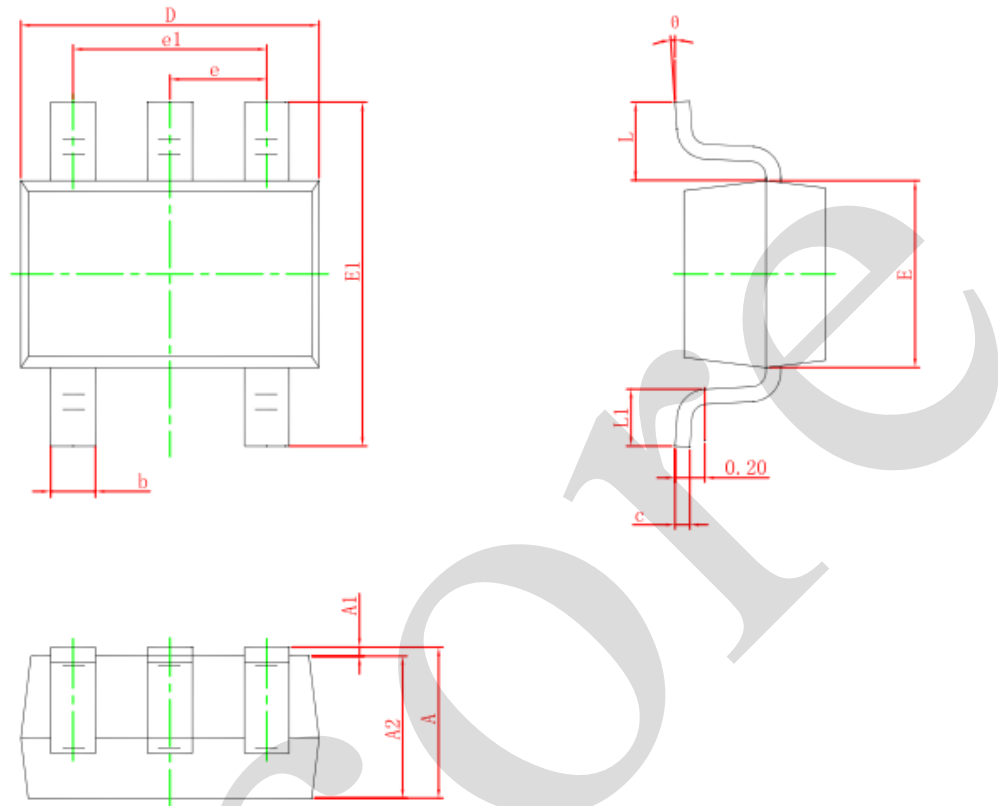
### 5.1、SOT-23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
$\theta$	0°	8°	0°	8°



## 5.2、SOT-353



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°



## 6、 Statements And Notes

### 6.1、 The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

### 6.2、 Notion

Recommended carefully reading this information before the use of this product;

The information in this document are subject to change without notice;

This information is using to the reference only, the company is not responsible for any loss;

The company is not responsible for the any infringement of the third party patents or other rights of the responsibility.